

Power transistor (60V, 3A)

2SC5825

●Features

- 1) High speed switching.
(Tf : Typ. : 30ns at Ic = 3A)
- 2) Low saturation voltage, typically
(Typ. : 200mV at Ic = 2A, Ib = 0.2mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2073

●Applications

Low frequency amplifier
High speed switching

●Structure

NPN Silicon epitaxial planar transistor

●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	2500
2SC5825		○

●Absolute maximum ratings (Ta=25°C)

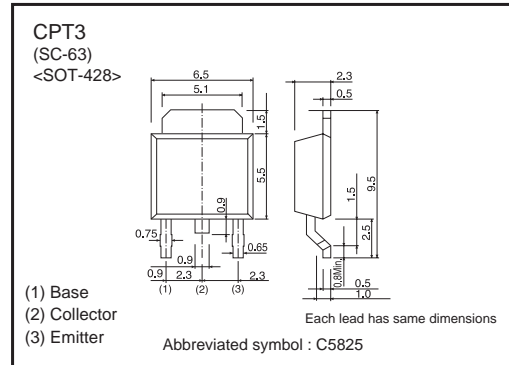
Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CE0}	60	V
Emitter-base voltage	V _{EB0}	6	V
Collector current	Continuous	I _c	3 A
	Pulsed	I _{cP}	6 A *1
Power dissipation	P _c	1.0	W *2
		10.0	W *3
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to 150	°C

*1 Pw=10ms

*2 Each terminal mounted on a recommended land

*3 Tc=25°C

●Dimensions (Unit : mm)



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV_{CEO}	60	–	–	V	$I_C=1mA$
Collector-base breakdown voltage	BV_{CBO}	60	–	–	V	$I_C=100\mu A$
Emitter-base breakdown voltage	BV_{EBO}	6	–	–	V	$I_E=100\mu A$
Collector cut-off current	I_{CBO}	–	–	1.0	μA	$V_{CB}=40V$
Emitter cut-off current	I_{EBO}	–	–	1.0	μA	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	200	500	mV	$I_C=2A$ $I_B=200mA$
DC current gain	h_{FE}	120	–	390	–	$V_{CE}=2V$ $I_C=100mA$
Transition frequency	f_T	–	200	–	MHz	$V_{CE}=10V$ $I_E=-100mA$ $f=10MHz$
Corrector output capacitance	C_{ob}	–	20	–	pF	$V_{CB}=10V$ $I_E=0mA$ $f=1MHz$
Turn-on time	T_{on}	–	50	–	ns	$I_C=3A$ $I_{B1}=300mA$ $I_{B2}=-300mA$ $V_{CC}\approx 25V$
Storage time	T_{stg}	–	150	–	ns	
Fall time	T_f	–	30	–	ns	

*1 Non repetitive pulse

*2 See Switching characteristics measurement circuits

●hFE RANK

Q	R
120–270	180–390

●Electrical characteristic curves

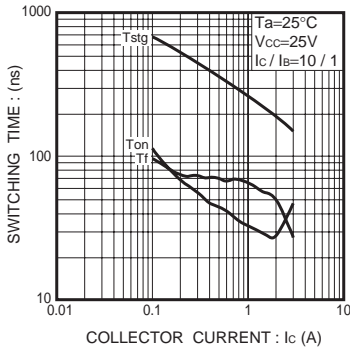


Fig.1 Switching Time

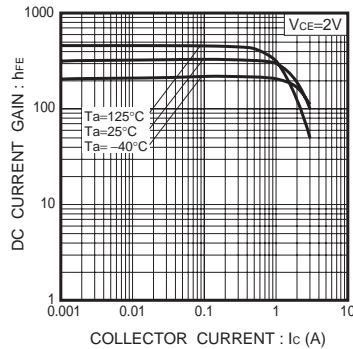


Fig.2 DC Current Gain vs. Collector Current (I)

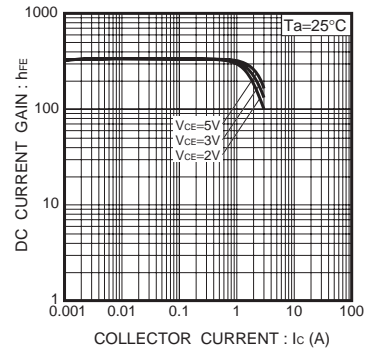


Fig.3 DC Current Gain vs. Collector Current (II)

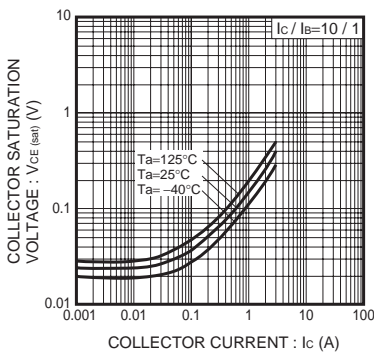


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

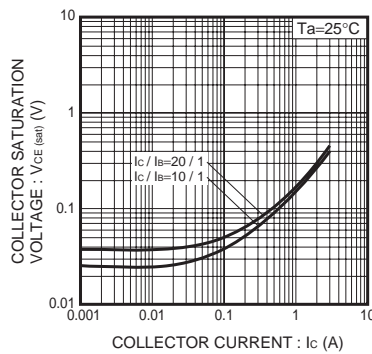


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

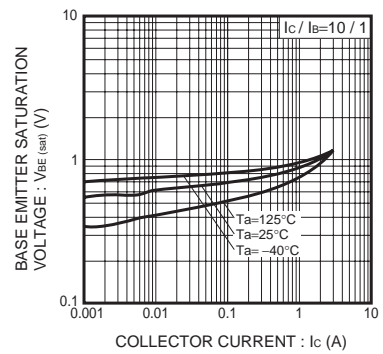


Fig.6 Base-Emitter Saturation Voltage vs. Collector Current

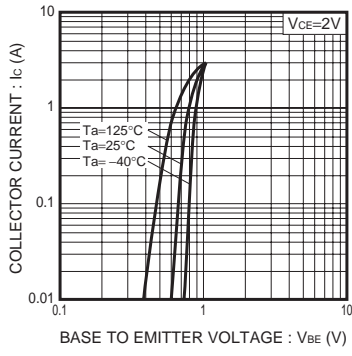


Fig.7 Grounded Emitter Propagation Characteristics

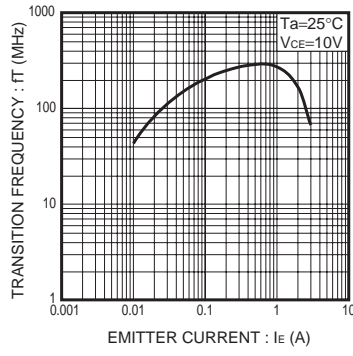


Fig.8 Transition Frequency

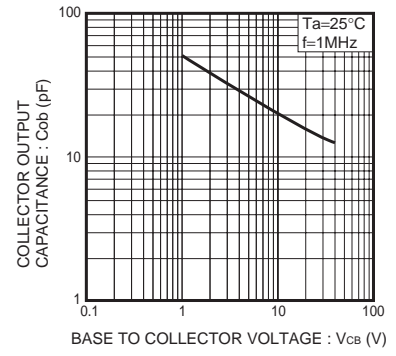
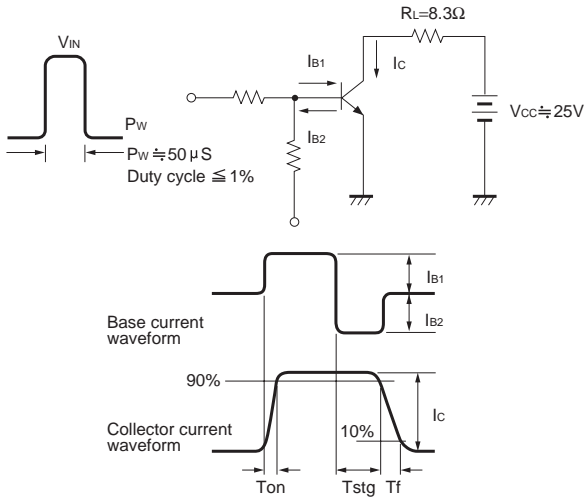


Fig.9 Collector Output Capacitance

●Switching characteristics measurement circuits



Notes

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